



# SANYO Semiconductors DATA SHEET

# **2SK3745LS**—High-Voltage, High-Speed Switching Applications

#### **Features**

- · Low ON-resistance, low input capacitance, ultrahigh-speed switching.
- · High reliability (Adoption of HVP process).
- Micaless package facilitating mounting.
- · Avalanche resistance guarantee.

#### **Specifications**

#### Absolute Maximum Ratings at Ta=25°C

| Parameter                          | Symbol | Conditions | Ratings     | Unit |
|------------------------------------|--------|------------|-------------|------|
| Drain-to-Source Voltage            | VDSS   |            | 1500        | V    |
| Gate-to-Source Voltage             | VGSS   |            | ±20         | V    |
| Drain Current (DC)                 | ID*    |            | 2           | Α    |
| Drain Current (Pulse)              | IDP    |            | 4           | Α    |
| Allowable Power Dissipation        | D-     |            | 2.0         | W    |
|                                    | PD     | Tc=25°C    | 35          | W    |
| Channel Temperature                | Tch    |            | 150         | °C   |
| Storage Temperature                | Tstg   |            | -55 to +150 | °C   |
| Avalanche Enargy (Single Pulse) *1 | EAS    |            | 42          | mJ   |
| Avalanche Current *2               | IAV    |            | 2           | Α    |

<sup>\*</sup>Shows chip capability

#### Electrical Characteristics at Ta=25°C

| Parameter                                  | Symbol               | Conditions                                  | Ratings |     |     | Unit |
|--|----------------------|---|---------|-----|-----|------|
|  |                      |   | min     | typ | max | Unit |
| Drain-to-Source Breakdown Voltage          | V(BR)DSS             | I <sub>D</sub> =1mA, V <sub>G</sub> S=0V    | 1500    |     |     | V    |
| Zero-Gate Voltage Drain Current            | IDSS                 | V <sub>DS</sub> =1200V, V <sub>GS</sub> =0V |         |     | 100 | μΑ   |
| Gate-to-Source Leakage Current             | IGSS                 | VGS= ±16V, VDS=0V                           |         |     | ±10 | μΑ   |
| Cutoff Voltage                             | VGS(off)             | V <sub>DS</sub> =10V, I <sub>D</sub> =1mA   | 2.5     |     | 3.5 | V    |
| Forward Transfer Admittance                | yfs                  | V <sub>DS</sub> =20V, I <sub>D</sub> =1A    | 0.7     | 1.4 |     | S    |
| Static Drain-to-Source On-State Resistance | R <sub>DS</sub> (on) | I <sub>D</sub> =1A, V <sub>G</sub> S=10V    |         | 10  | 13  | Ω    |

Marking: K3745 Continued on next page.

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<sup>\*1</sup> V<sub>DD</sub>=99V, L=20mH, I<sub>A</sub>V=2A

<sup>\*2</sup> L≤20mH, single pulse

#### 2SK3745LS

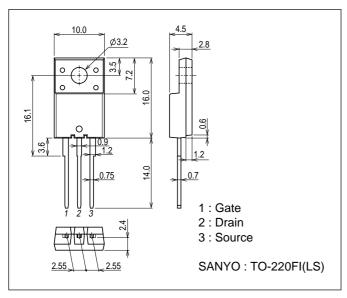
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| Parameter                     | Symbol               | Conditions  |     | Ratings |     |      |
|-------------------------------|----------------------|---|-----|---------|-----|------|
|                               | Symbol               |   | min | typ     | max | Unit |
| Input Capacitance             | Ciss                 | V <sub>DS</sub> =30V, f=1MHz                                    |     | 380     |     | pF   |
| Output Capacitance            | Coss                 | V <sub>DS</sub> =30V, f=1MHz                                    |     | 70      |     | pF   |
| Reverse Transfer Capacitance  | Crss                 | VDS=30V, f=1MHz   |     | 40      |     | pF   |
| Turn-ON Delay Time            | t <sub>d</sub> (on)  | See specified Test Circuit.                                     |     | 12      |     | ns   |
| Rise Time                     | t <sub>r</sub>       | See specified Test Circuit.                                     |     | 37      |     | ns   |
| Turn-OFF Delay Time           | t <sub>d</sub> (off) | See specified Test Circuit.                                     |     | 152     |     | ns   |
| Fall Time                     | tf                   | See specified Test Circuit.                                     |     | 59      |     | ns   |
| Total Gate Charge             | Qg                   | V <sub>DS</sub> =200V, V <sub>GS</sub> =10V, I <sub>D</sub> =2A |     | 37.5    |     | nC   |
| Gate-to-Source Charge         | Qgs                  | V <sub>D</sub> S=200V, V <sub>G</sub> S=10V, I <sub>D</sub> =2A |     | 2.7     |     | nC   |
| Gate-to-Drain "Miller" Charge | Qgd                  | V <sub>DS</sub> =200V, V <sub>GS</sub> =10V, I <sub>D</sub> =2A |     | 20      |     | nC   |
| Diode Forward Voltage         | V <sub>SD</sub>      | I <sub>S</sub> =2A, V <sub>GS</sub> =0V                         |     | 0.88    | 1.2 | V    |

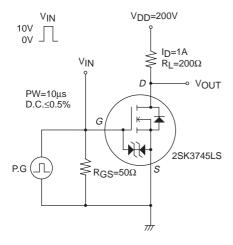
Note) Although the protection diode is contained between gate and source, be careful of handling enough.

#### **Package Dimensions**

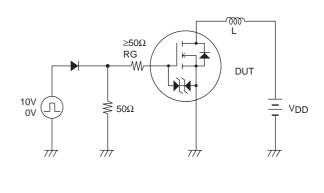
unit : mm 7509-002

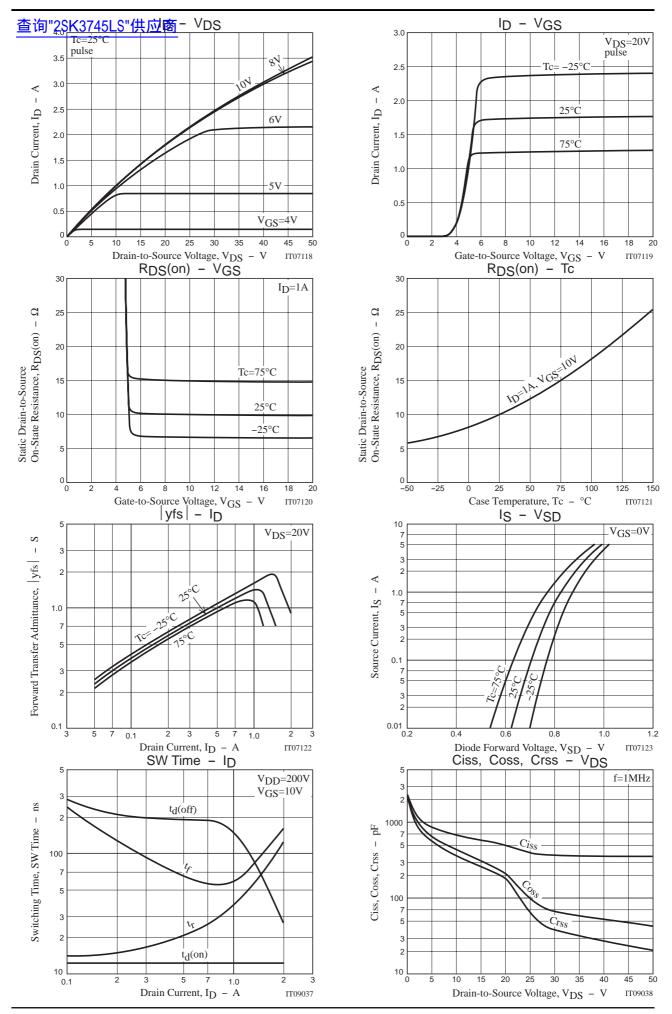


## **Switching Time Test Circuit**

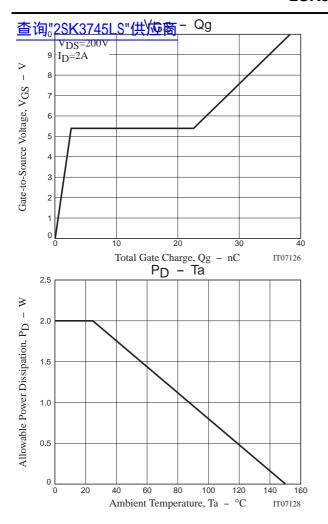


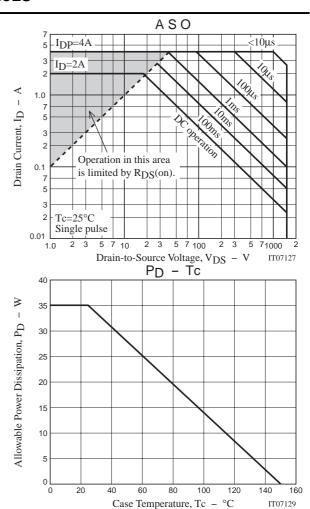
# **Avalanche Resistance Test Circuit**





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